NSN 5962-00-163-6292

Memory Microcircuit - Page 1 of 1



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Body Length:
Between 0.660 inches and 0.785 inches
Body Width:
Between 0.220 inches and 0.280 inches
Body Height:
Between 0.140 inches and 0.180 inches
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
Features Provided:
Hermetically sealed and monolithic and positive outputs
Inclosure Material:
Glass and metal
Inclosure Configuration:
Dual-in-line
Output Logic Form:
Transistor-transistor logic
Input Circuit Pattern:
8 input
Case Outline Source And Designator:
T0-116 joint electron device engineering council
Terminal Surface Treatment:
Solder
Voltage Rating And Type Per Characteristic:
-1.5 volts power source and 5.5 volts power source
Time Rating Per Chacteristic:
50.00 nanoseconds propagation delay time, low to high level output and 50.00 nanoseconds propagation delay time, high to low level
output
Memory Device Type:
Diode matrix
Terminal Type And Quantity:
14 printed circuit
Shelf Life:
N/a
Unit Of Measure:
Domilitarination.
Demilitarization:
Yes - demil/mli

Fiig:

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